Unit: mm

#### TOSHIBA Photocoupler InGaAs Infrared LED & Photo Transistor

# **TLP183**

Office Machine
Programmable Controllers
AC Adapter
I/O Interface Board

TLP183 consist of a photo transistor optically coupled to an InGaAs infrared emitting diode.

TLP183 is a low input type phototransistor coupler that housed in the very small and thin SO6 package. It is guaranteed wide operating temperature (Ta = -55 to 125 °C) and high isolation voltage (3750Vrms).

TLP183 is smaller than DIP package; it's suitable for high-density surface mounting applications such as programmable controllers

Collector-emitter voltage: 80V (min)

• Current transfer ratio: 50% (min)

Rank GB: 100% (min)

• Isolation voltage: 3750Vrms (min)

• Operation Temperature:-55 to 125 °C

Safety Standards

UL recognized: UL1577, File No. E67349

cUL approved: CSA Component Acceptance Service No. 5A

File No. E67349

• Option (V4) type

VDE approved: DIN EN60747-5-5, File No. 40009347 (Note): When a EN60747-5-5 approved type is needed,

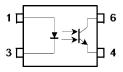
Please designate "Option(V4)" Construction mechanical rating

Creepage distance : 5.0 mm(min)
Clearance : 5.0 mm(min)
Insulation thickness : 0.4 mm(min)

JEDEC 
JIETA 
TOSHIBA 11-4M1S

Weight: 0.08 g (Typ.)

#### **Pin Configuration**



- 1: Anode
- 3: Cathode
- 4: Emitter
- 6: Collector



## **Current Transfer Ratio (Unless otherwise specified, Ta = 25°C)**

| Rank    |  | Current Transfer Ratio          |     |                            | Unit |  |
|---------|--|---------------------------------|-----|----------------------------|------|--|
| (Note1) | Test Condition                                 | I <sub>C</sub> / I <sub>F</sub> |     | Marking Of Classification  |      |  |
|         |  | Min                             | Max |                            |      |  |
| Blank   | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$     | 50                              | 600 | Blank, YE, GR, GB, BL, Y+, |      |  |
| Biariik | $I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$   | 00                              | 000 | G, G+, B                   |      |  |
| Υ       | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$     | 50                              | 150 | YE                         | 1    |  |
|         | $I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$   |                                 |     |                            |      |  |
| GR      | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$     | 100                             | 300 | GR                         |      |  |
|         | $I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$   |                                 |     |                            |      |  |
| GB      | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$     | 100                             | 600 | GB                         |      |  |
|         | $I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$   |                                 |     |                            |      |  |
| BL      | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$     | 200                             | 600 | BL                         | %    |  |
|         | $I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$   |                                 |     |                            | 70   |  |
| YH      | I <sub>F</sub> = 0.5 mA, V <sub>CE</sub> = 5 V | 75                              | 150 | Y+                         |      |  |
| GRL     | I <sub>F</sub> = 0.5 mA, V <sub>CE</sub> = 5 V | 100                             | 200 | G                          |      |  |
| GRH     | I <sub>F</sub> = 0.5 mA, V <sub>CE</sub> = 5 V | 150                             | 300 | G+                         |      |  |
| BLL     | I <sub>F</sub> =0.5 mA, V <sub>CE</sub> = 5 V  | 200                             | 400 | В                          |      |  |

Note1: Specify both the part number and a rank in this format when ordering

(e.g.) rank GB: TLP183 (GB,E

For safety standard certification, however, specify the part number alone.

(e.g.)TLP183 (GB,E: TLP183

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### Absolute Maximum Ratings (Unless otherwise specified, Ta = 25°C)

| Characteristic                  |   | Symbol                | Note     | Rating     | Unit             |  |
|---------------------------------|---|-----------------------|----------|------------|------------------|--|
| Input forward current           |   | l <sub>F</sub>        |          | 50         | mA               |  |
|                                 | Input forward current derating (Ta ≥ 90°C)        |                       |          | -1.5       | mA / °C          |  |
| LED                             | Input forward current (Pulsed)                    | I <sub>FP</sub>       | (Note2)  | 1          | А                |  |
|                                 | Input reverse voltage                             | V <sub>R</sub>        |          | 5          | V                |  |
|                                 | Junction temperature                              | Tj                    |          | 125        | °C               |  |
|                                 | Collector-emitter voltage                         | V <sub>CEO</sub>      |          | 80         | V                |  |
|                                 | Emitter-collector voltage                         | V <sub>ECO</sub>      |          | 7          | V                |  |
| ctor                            | Collector current                                 | I <sub>C</sub>        |          | 50         | mA               |  |
| Detector                        | Collector power dissipation                       | PC                    |          | 150        | mW               |  |
|                                 | Collector power dissipation derating (Ta ≥ 25°C)  | ΔP <sub>C</sub> / ΔTa |          | -1.5       | mW / °C          |  |
|                                 | Junction temperature                              | Tj                    |          | 125        | °C               |  |
| Оре                             | erating temperature range                         | T <sub>opr</sub>      |          | −55 to 125 | °C               |  |
| Stor                            | Storage temperature range                         |                       |          | −55 to 125 | °C               |  |
| Lead soldering temperature      |   | T <sub>sol</sub>      |          | 260 (10s)  | °C               |  |
| Total package power dissipation |   | P <sub>T</sub>        |          | 200        | mW               |  |
| Tota                            | al package power dissipation derating (Ta ≥ 25°C) | ΔP <sub>T</sub> / ΔTa |          | -2.0       | mW / °C          |  |
| Isolation voltage               |   | BVS                   | (Note 3) | 3750       | V <sub>rms</sub> |  |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Pulse width ≤ 100 μs,f=100 Hz

Note 3: AC, 1min., R.H.≤ 60%, Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

## Individual Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

| Characteristic |                                     | Symbol                | Test Condition                    | Min | Тур. | Max  | Unit |
|----------------|-------------------------------------|-----------------------|-----------------------------------|-----|------|------|------|
|                | Input forward voltage               | V <sub>F</sub>        | I <sub>F</sub> = 10 mA            | 1.1 | 1.25 | 1.4  | V    |
| LED            | Input reverse current               | I <sub>R</sub>        | V <sub>R</sub> = 5 V              | -   | -    | 5    | μΑ   |
|                | Input capacitance                   | C <sub>T</sub>        | V = 0V, f = 1 MHz                 | -   | 30   | -    | pF   |
|                | Collector-emitter breakdown voltage | V <sub>(BR)</sub> CEO | I <sub>C</sub> = 0.5 mA           | 80  | -    | -    | V    |
| ō              | Emitter-collector breakdown voltage | V <sub>(BR)</sub> ECO | I <sub>E</sub> = 0.1 mA           | 7   | -    | -    | V    |
| Detector       | Dark current                        | l= . =                | V <sub>CE</sub> = 48 V            | -   | 0.01 | 0.08 | μΑ   |
| Dark current   | Dark Current                        | IDARK                 | V <sub>CE</sub> = 48 V, Ta = 85°C | -   | 2    | 50   | μΑ   |
|                | Collector-emitter capacitance       | C <sub>CE</sub>       | V = 0V, f = 1 MHz                 | -   | 10   | -    | pF   |

## **Coupled Electrical Characteristics (Unless otherwise specified, Ta = 25°C)**

| Characteristic                       | Symbol                                | Test Condition  | MIn | Тур. | Max | Unit |
|--------------------------------------|---------------------------------------|---|-----|------|-----|------|
|                                      | I <sub>C</sub> / I <sub>F</sub>       | $I_F$ = 5 mA, $V_{CE}$ = 5 V Rank GB                      | 50  | -    | 600 | - %  |
| Current transfer ratio               |                                       |   | 100 | ı    | 600 |      |
| Current transfer ratio               |                                       | I <sub>F</sub> = 0.5 mA, V <sub>CE</sub> = 5 V<br>Rank GB | 50  | -    | 600 |      |
|                                      |                                       |   | 100 | -    | 600 |      |
| Saturated current transfer ratio     | I <sub>C</sub> / I <sub>F (sat)</sub> | IF = 1 mA, V <sub>CE</sub> = 0.4 V<br>Rank GB             | ı   | 60   | ı   | - %  |
| Saturated Current transfer ratio     |                                       |   | 30  | 1    | 1   |      |
| Collector-emitter saturation voltage | V <sub>CE</sub> (sat)                 | I <sub>C</sub> = 2.4 mA, I <sub>F</sub> = 8 mA            | -   | -    | 0.3 |      |
|                                      |                                       | I <sub>C</sub> = 0.2 mA, I <sub>F</sub> = 1 mA<br>Rank GB | -   | 0.2  | -   | V    |
|                                      |                                       |   | -   | -    | 0.3 |      |
| Off-state collector current          | I <sub>C (off)</sub>                  | V <sub>F</sub> = 0.7V, V <sub>CE</sub> = 48 V             | -   | -    | 10  | μΑ   |

## Isolation Characteristics (Unless otherwise specified, Ta = 25°C)

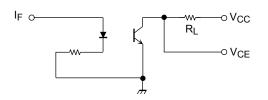
| Characteristic                      | Symbol                  | Test Condition                     | Min                | Тур.             | Max | Unit               |
|-------------------------------------|-------------------------|------------------------------------|--------------------|------------------|-----|--------------------|
| Total capacitance (input to output) | CS                      | V <sub>S</sub> = 0V, f = 1 MHz     | -                  | 0.8              | -   | pF                 |
| Isolation resistance                | R <sub>S</sub>          | V <sub>S</sub> = 500 V, R.H. ≤ 60% | 1×10 <sup>12</sup> | 10 <sup>14</sup> | -   | Ω                  |
| Isolation voltage                   | BV <sub>S</sub> AC, 1 s | AC, 1 minute                       | 3750               | -                | -   | - V <sub>rms</sub> |
|                                     |                         | AC, 1 second, in oil               | -                  | 10000            | -   |                    |
|                                     |                         | DC, 1 minute, in oil               | -                  | 10000            | -   | V <sub>dc</sub>    |

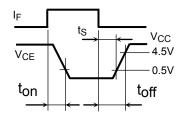
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## Switching Characteristics (Unless otherwise specified, Ta = 25°C)

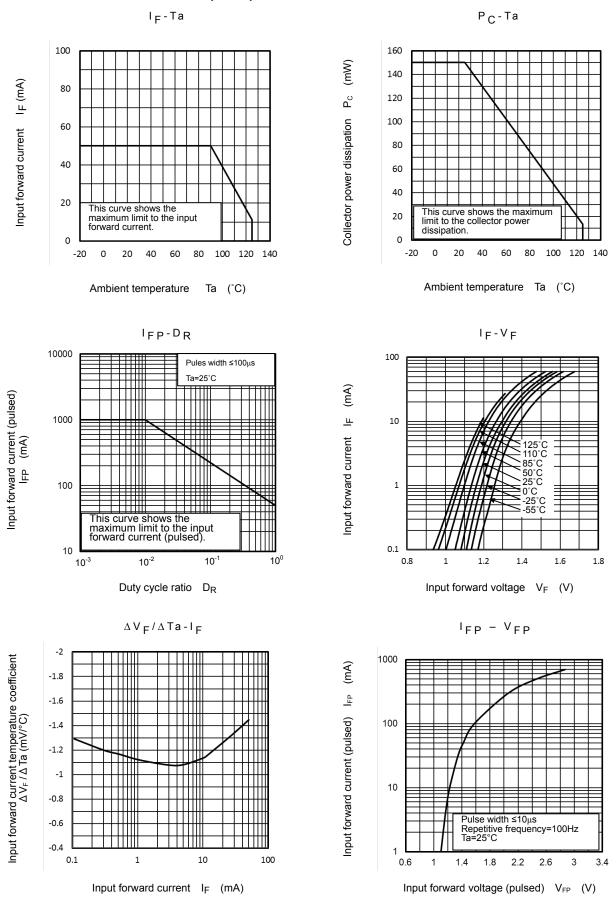
| Characteristic | Symbol           | Test Condition   | Min | Тур. | Max | Unit |
|----------------|------------------|--|-----|------|-----|------|
| Rise time      | t <sub>r</sub>   | $V_{CC}$ = 10 V, I <sub>C</sub> = 2 mA<br>R <sub>L</sub> = 100 $\Omega$            | -   | 2    | -   |      |
| Fall time      | t <sub>f</sub>   |  | -   | 3    | -   |      |
| Turn-on time   | t <sub>on</sub>  |  | -   | 3    | -   |      |
| Turn-off time  | t <sub>off</sub> |  | -   | 3    | -   | μS   |
| Turn-on time   | ton              |  | -   | 0.4  | -   |      |
| Storage time   | ts               | $R_L = 1.9 \text{ k}\Omega$ (Fig.1)<br>$V_{CC} = 5 \text{ V}, I_F = 16 \text{ mA}$ | -   | 20   | -   |      |
| Turn-off time  | toff             |  | -   | 35   | -   |      |
| Turn-on time   | t <sub>on</sub>  |  | -   | 4    | -   |      |
| Storage time   | t <sub>S</sub>   | $R_L = 1.9 \text{ k}\Omega$ (Fig.1)<br>$V_{CC} = 5 \text{ V}, I_F = 16 \text{ mA}$ | -   | 7    | -   | μS   |
| Turn-off time  | t <sub>off</sub> |  | -   | 30   | -   |      |

Fig. 1 Switching time test circuit

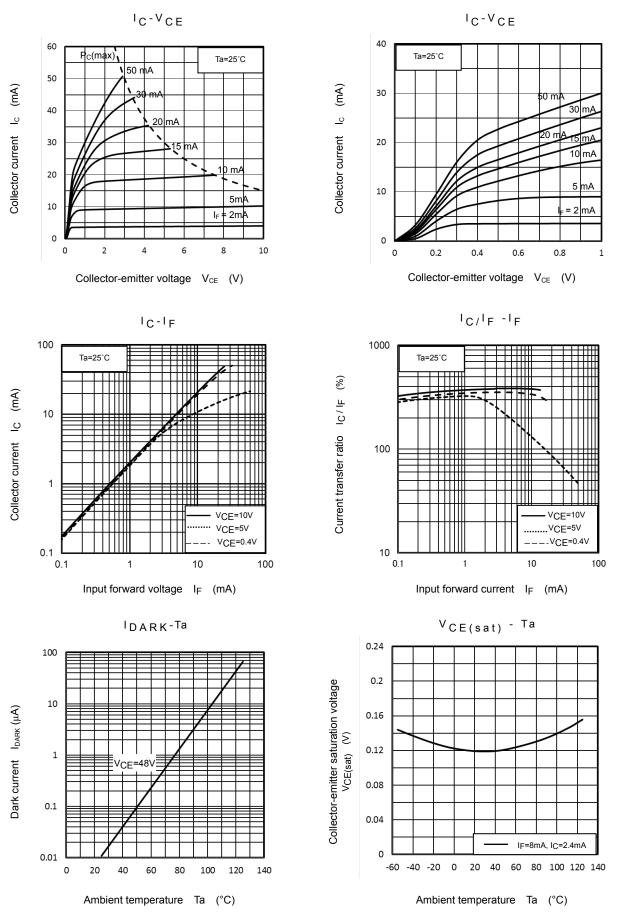




#### **Characteristics Curves (Note)**

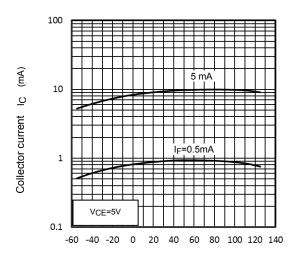


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted



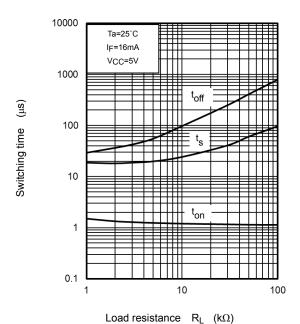
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted

I<sub>C</sub> - Ta

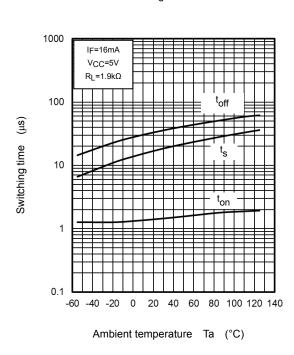


Ambient temperature Ta (°C)

Switching time - R<sub>L</sub>



Switching time - Ta



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## Soldering and Storage

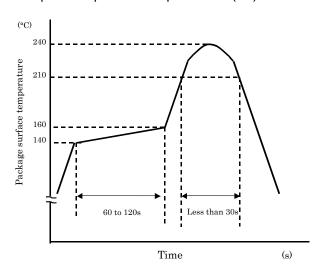
#### 1. Soldering

#### 1.1 Soldering

When using a soldering iron or medium infrared ray/hot air reflow, avoid a rise in device temperature as much as possible by observing the following conditions.

#### 1) Using solder reflow

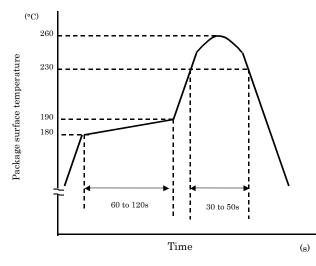
·Temperature profile example of lead (Pb) solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

·Temperature profile example of using lead (Pb)-free solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

2) Using solder flow (for lead (Pb) solder, or lead (Pb)-free solder)

Please preheat it at 150°C between 60 and 120 seconds.

Complete soldering within 10 seconds below 260°C. Each pin may be heated at most once.

3) Using a soldering iron

Complete soldering within 10 seconds below 260°C, or within 3 seconds at 350°C. Each pin may be heated at most once.

#### 2. Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

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